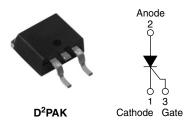


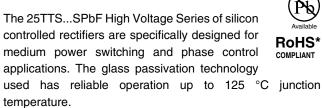
Vishay High Power Products

Surface Mountable Phase Control SCR, 16 A



PRODUCT SUMMARY			
V _T at 16 A	< 1.25 V		
I _{TSM}	300 A		
V_{RRM}	800 to 1600 V		

DESCRIPTION/FEATURES



Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level and lead (Pb)-free ("PbF" suffix).

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS					
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 μm) copper	3.5	5.5			
Aluminum IMS, R _{thCA} = 15 °C/W	8.5	13.5	A		
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	16.5	25.0			

Note

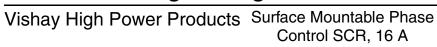
• $T_A = 55$ °C, $T_J = 125$ °C, footprint 300 mm²

PARAMETER	TEST CONDITIONS	VALUES	UNITS
I _{T(AV)}	Sinusoidal waveform	16	^
I _{RMS}		25	A
V _{RRM} /V _{DRM}		800 to 1600	V
I _{TSM}		300	Α
V_{T}	16 A, T _J = 25 °C	1.25	V
dV/dt		500	V/µs
dl/dt		150	A/μs
TJ		- 40 to 125	°C

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} , AT 125 °C mA			
25TTS08SPbF	800	800				
25TTS12SPbF	1200	1200	10			
25TTS16SPbF	1600	1600				

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COMPLETIONS		VALUES		
PARAMETER	STINIBUL	153	TEST CONDITIONS		MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 180° cor	nduction half sine wave	1	6	
Maximum RMS on-state current	I _{RMS}			2	25	A
Maximum peak, one-cycle,	-	10 ms sine pulse, rat	ted V _{RRM} applied	3	00	A
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no	voltage reapplied	3	350	
Maximum 12+ for fusing	l ² t	10 ms sine pulse, rat	ted V _{RRM} applied	4	50	A2a
Maximum I ² t for fusing	I-t	10 ms sine pulse, no voltage reapplied		6	630	A ² s
Maximum I $^2\sqrt{t}$ for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		63	300	A²√s
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C		1.	25	V
On-state slope resistance	r _t	r _t T. = 125 °C		12	2.0	mΩ
Threshold voltage	V _{T(TO)}	T _J = 125 °C		1	.0	V
Maximum various and divest leakens accurant	1 /1			0	.5	
Maximum reverse and direct leakage current	I_{RM}/I_{DM}			1	0	
Holding ourront	I _H	25TTS08, 25TTS12	Anode supply = 6 V,	-	100	mA
Holding current		25TTS16	resistive load, initial $I_T = 1 A$	100	150	1
Maximum latching current	ΙL	Anode supply = 6 V, resistive load		2	00	
Maximum rate of rise of off-state voltage	dV/dt	500		00	V/µs	
Maximum rate of rise of turned-on current	dl/dt			1:	50	A/μs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}		8.0	w
Maximum average gate power	P _{G(AV)}		2.0	l vv
Maximum peak positive gate current	+ I _{GM}		1.5	Α
Maximum peak negative gate voltage	- V _{GM}		10	V
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	60	mA
		Anode supply = 6 V, resistive load, T _J = 25 °C	45	
		Anode supply = 6 V, resistive load, T _J = 125 °C	20	
		Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5	
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	V
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	\ \
Maximum DC gate voltage not to trigger	V_{GD}	T _J = 125 °C, V _{DRM} = Rated value 0.25 2.0		
Maximum DC gate current not to trigger	I _{GD}			mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T 105 °C	4	μs
Typical turn-off time	tq	T _J = 125 °C	110	



Surface Mountable Phase Vishay High Power Products Control SCR, 16 A

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C	
Soldering temperature	T _S	For 10 s (1.6 mm from case)	240		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.1 °C/W		
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} (1)		40	0/11	
Approximate weight			2	g	
Approximate weight			0.07	oz.	
			25TTS0	18S	
Marking device		Case style D ² PAK (SMD-220)	25TTS1	2S	
			25TTS1	6S	

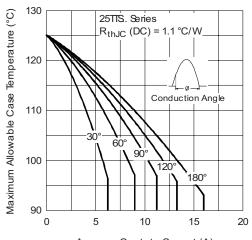
Note

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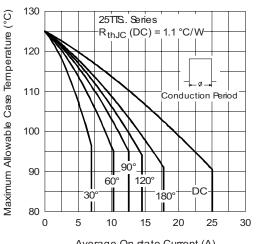
 $^{^{(1)}}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 $\mu m]$ copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

Vishay High Power Products Surface Mountable Phase Control SCR, 16 A





Average On-state Current (A)
Fig. 1 - Current Rating Characteristics



Average On-state Current (A)
Fig. 2 - Current Rating Characteristics

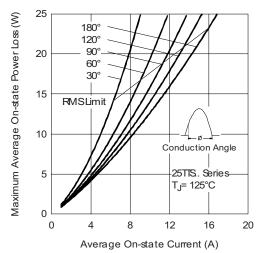


Fig. 3 - On-State Power Loss Characteristics

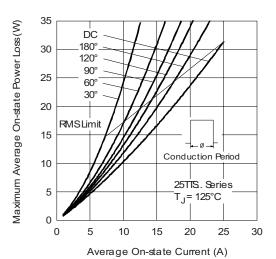


Fig. 4 - On-State Power Loss Characteristics

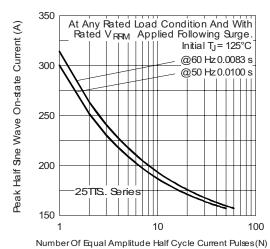


Fig. 5 - Maximum Non-Repetitive Surge Current

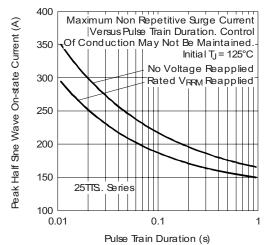


Fig. 6 - Maximum Non-Repetitive Surge Current



Surface Mountable Phase Vishay High Power Products Control SCR, 16 A

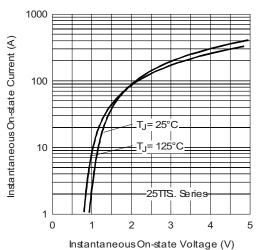
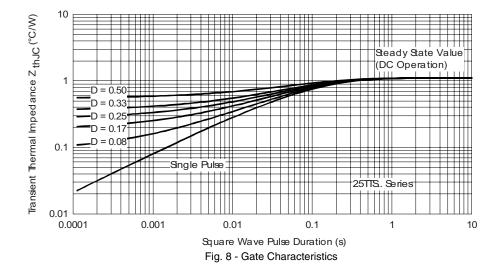


Fig. 7 - On-State Voltage Drop Characteristics



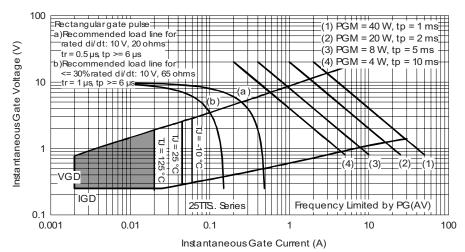
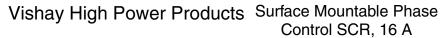


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics





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ORDERING INFORMATION TABLE

Device code 25 Т Т S 12 S **TRL PbF** (2)(3)(4) (5) (6)Current rating (25 = 25 A) Circuit configuration: T = Single thyristor Package: 3 T = TO-220AC Type of silicon: Standard recovery rectifier 08 = 800 V Voltage rating = Voltage code x 100 = V_{RRM} 12 = 1200 V 16 = 1600 V $S = TO-220 D^2PAK (SMD-220) version$ • None = Tube • TRL = Tape and reel (left oriented) • TRR = Tape and reel (right oriented) 8 • None = Standard production • PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95046			
Part marking information	http://www.vishay.com/doc?95054		
Packaging information	http://www.vishay.com/doc?95032		



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